## BUT211X

#### **GENERAL DESCRIPTION**

Enhanced performance, new generation, high speed switching npn transistor in a plastic full-pack envelope specially suited for high frequency electronic lighting ballast applications.

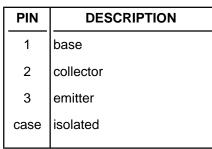
#### QUICK REFERENCE DATA

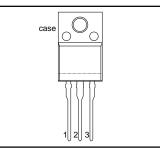
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V <sub>CESM</sub>	Collector-emitter voltage peak value	$V_{BE} = 0 V$	-	850	V
V <sub>CEO</sub>	Collector-emitter voltage (open base)		-	400	V
I <sub>c</sub>	Collector current (DC)		-	5	Α
11	Collector current peak value		-	10	Α
I <sub>СМ</sub> Р <sub>tot</sub>	Total power dissipation	T <sub>hs</sub> ≤ 25 °C	-	32	W
V <sub>CEsat</sub>	Collector-emitter saturation voltage	$I_{\rm C} = 3.0 \text{ A}; I_{\rm B} = 0.4 \text{ A}$	-	2.0	V
t <sub>f</sub>	Inductive fall time	$I_{Con} = 3.0 \text{ A}; I_{Bon} = 0.3 \text{ A}$	-	0.1	μs

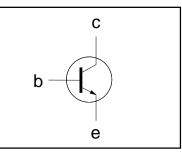
#### PINNING - SOT186A

#### PIN CONFIGURATION

#### SYMBOL







#### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CESM</sub>	Collector-emitter voltage peak value	$V_{BE} = 0 V$	-	850	V
V <sub>CEO</sub>	Collector-emitter voltage (open base)		-	400	V
I <sub>C</sub>	Collector current (DC)		-	5	A
I <sub>CM</sub>	Collector current peak value		-	10	A
I <sub>B</sub>	Base current (DC)		-	2	A
I <sub>BM</sub>	Base current peak value		-	4	A
P <sub>tot</sub>	Total power dissipation	$T_{hs} \leq 25 \degree C$	-	32	W
T <sub>stq</sub>	Storage temperature		-65	150	°C
$ T_j $	Junction temperature		-	150	°C

#### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R <sub>th j-hs</sub>	Junction to heat sink		-	3.95	K/W
R <sub>th j-a</sub>	Junction to ambient	in free air	-	55	K/W

## **BUT211X**

## **ISOLATION LIMITING VALUE & CHARACTERISTIC**

 $T_{hs} = 25$  °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>isol</sub>	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. $\leq$ 65% ; clean and dustfree	-		2500	V
C <sub>isol</sub>	Capacitance from T2 to external heatsink	f = 1 MHz	-	10	-	pF

#### STATIC CHARACTERISTICS

 $T_{hs} = 25$  °C unless otherwise specified

SYMBOL	PARAMETER		CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CES</sub> I <sub>CES</sub>	Collector cut-off current <sup>1</sup>			-	-	1.0 2.0	mA mA
$\begin{array}{l} I_{EBO} \\ V_{CEOsust} \end{array} \\ \begin{array}{c} V_{CEsat} \\ V_{BEsat} \\ h_{FE} \\ h_{FE} \end{array} \end{array}$	Emitter cut-off current Collector-emitter sustaining voltage Collector-emitter saturation voltage Base-emitter saturation voltage DC current gain		$V_{EB} = 9.0 \text{ V}; I_{C} = 0 \text{ A}$ $I_{B} = 0 \text{ A}; I_{C} = 100 \text{ mA};$ $L = 25 \text{ mH}$ $I_{C} = 3.0 \text{ A}; I_{B} = 0.4 \text{ A}$ $I_{C} = 3.0 \text{ A}; V_{E} = 2 \text{ V}$ $I_{C} = 3.0 \text{ A}; V_{CE} = 2 \text{ V}$	- 400 - 13 7.5	- - 0.8 - 21 11	10.0 - 2.0 1.3 30 -	mA V V V
h <sub>FE</sub>	Gain bands²1(Acceptance limits)23	2	$I_{c} = 1.0 \text{ A}; V_{ce} = 2 \text{ V}$	13 18 23		20 25 30	

#### **DYNAMIC CHARACTERISTICS**

 $T_{hs} = 25$  °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
t <sub>s</sub> t <sub>f</sub>	Switching times resistive load Turn-off storage time Turn-off fall time	$I_{Con} = 3.0 \text{ A}; I_{Bon} = 0.3 \text{ A}; -I_{Boff} = 0.6 \text{ A}$	1.5 0.5	2.0 0.8	μs μs
	Switching times inductive load	$I_{Con} = 3.0 \text{ A}; I_{Bon} = 0.3 \text{ A}; L_{B} = 1 \ \mu\text{H}; -V_{BB} = 5 \ V$			
t <sub>s</sub> t <sub>f</sub>	Turn-off storage time Turn-off fall time		1.0 60	1.2 100	μs ns
t <sub>s</sub> t <sub>f</sub>	Turn-off storage time Turn-off fall time	$ I_{Con} = 3.0 \text{ A}; I_{Bon} = 0.3 \text{ A}; L_{B} = 1  \mu\text{H}; \\ -V_{BB} = 5 \text{ V};  T_{j} = 100 ^{\circ}\text{C} $	1.1 120	1.4 250	μs ns

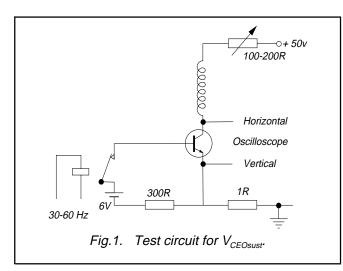
<sup>1</sup> Measured with half sine-wave voltage (curve tracer).

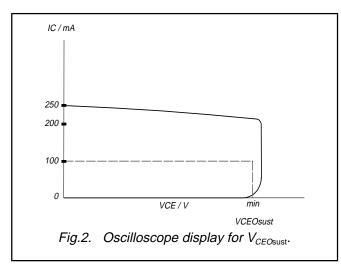
<sup>2</sup> Gain Banding.

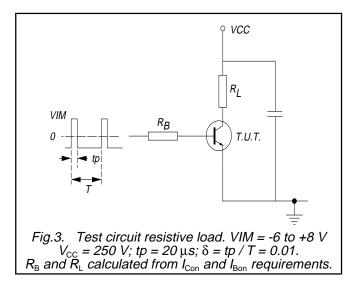
Product is divided into 3 gain bands for matching purposes. The gain band is printed on the device. All devices within a device rail will be from the same gain band. However, a box may contain rails from more than one band. Band quantities are shown on the box label.

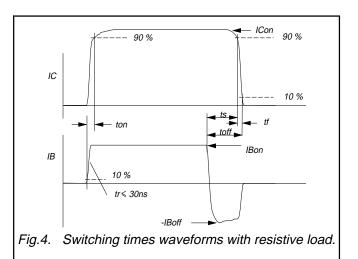
It is not possible to order specific gain bands.

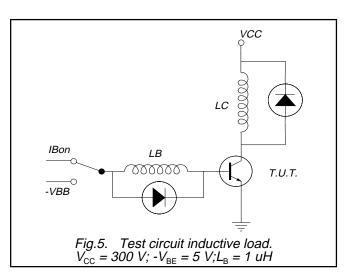
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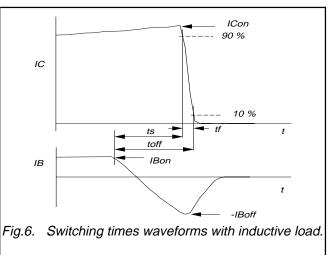




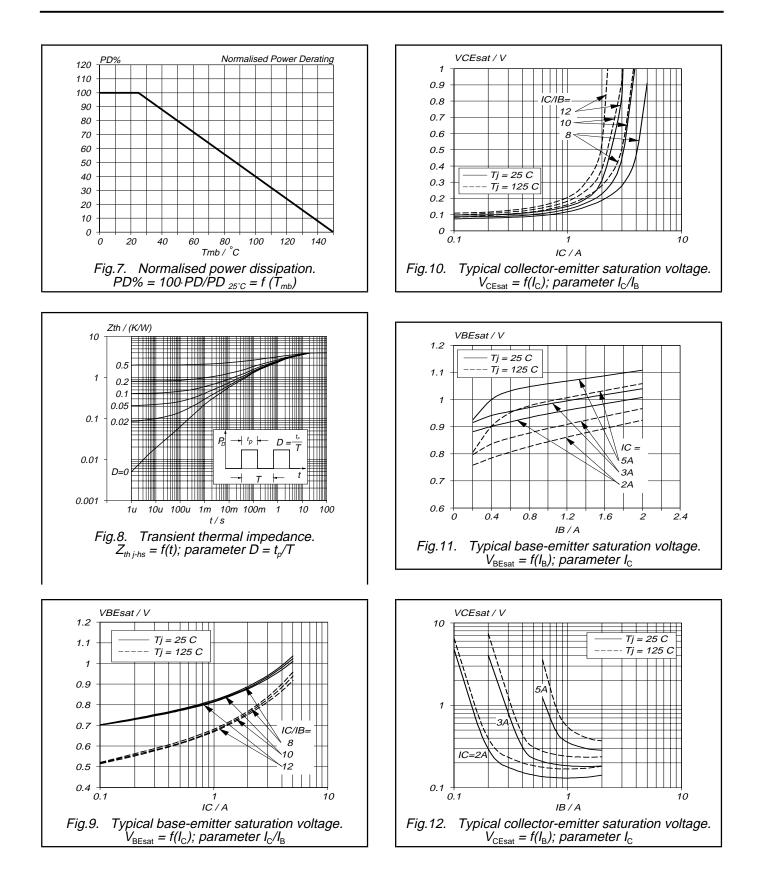




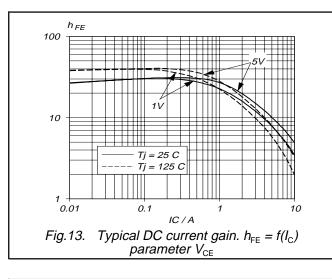


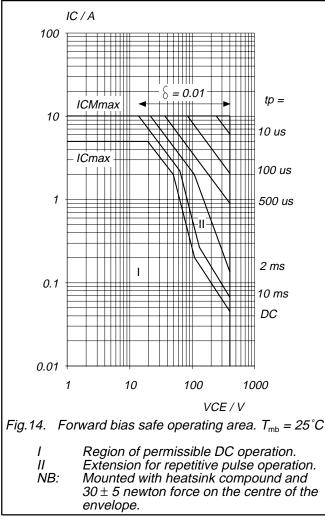


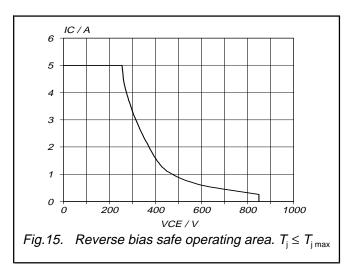
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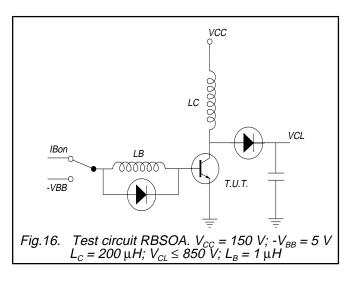


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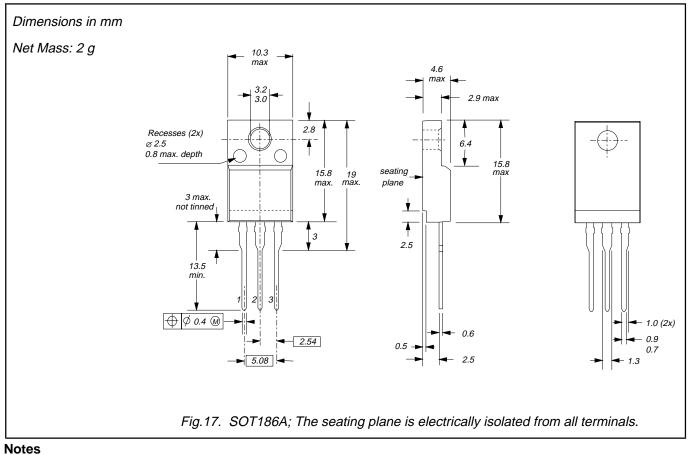




# Product specification

## BUT211X

#### **MECHANICAL DATA**



Refer to mounting instructions for F-pack envelopes.
 Epoxy meets UL94 V0 at 1/8".

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#### DEFINITIONS

Data sheet status					
Objective specification This data sheet contains target or goal specifications for product development.					
Preliminary specification This data sheet contains preliminary data; supplementary data may be published later					
Product specification	This data sheet contains final product specifications.				
Limiting values					
or more of the limiting val operation of the device at	Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				
Application information					
Where application information is given, it is advisory and does not form part of the specification.					
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